

# **Current Transducer LA 100-P**

For the electronic measurement of currents: DC, AC, pulsed..., with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).



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## Electrical data

I <sub>PN</sub>	Primary nominal r.m.s. current			100			Α
I <sub>P</sub>	Primary current, measuring range			0 ± 150			Α
$\mathbf{R}_{\mathrm{M}}$	Measuring resistance @ T		$T_A =$	70°C	<b>T</b> _A :	= 85°C	
			R <sub>M mir</sub>	$\mathbf{R}_{M\ max}$	R <sub>M mir</sub>	$\mathbf{R}_{M\ max}$	
	with ± 12 V	@ $\pm 100 A_{max}$	0	50	0	42	$\Omega$
		@ ± 120 A <sub>max</sub>	0	22	0	14	Ω
	with ± 15 V	@ $\pm 100 A_{max}$	0	110	20	102	Ω
		@ ± 150 A <sub>max</sub>	0	33	20	25	Ω
I <sub>SN</sub>	Secondary nominal r.m.s. current			50			mΑ
K <sub>N</sub>	Conversion ratio			1:3	2000		
<b>v</b> <sub>c</sub>	Supply voltage (±5 %)			± 1	2 1	5	V
I <sub>C</sub>	Current consumption			10(	10(@±15V)+ <b>I</b> <sub>s</sub>		mA
<b>V</b> <sub>d</sub>	R.m.s. voltage for AC iso	lation test, 50 Hz, 1	mn	2.5			k۷

### **Accuracy - Dynamic performance data**

Accuracy @  $I_{PN}$ ,  $T_{A} = 25$ °C

	@ ± 12	+ 0.70		%
Linearity	⊕ ± 12 13 V (± 3 %)			% %
		Тур	Max	
Offset current @ $I_p = 0$ , $T_A = 25$	°C		± 0.10	mA
Residual current $^{1}$ @ $I_p = 0$ , after an overload of 3 x $I_{pN}$			± 0.15	mA
Thermal drift of I	- 25°C + 85°C	± 0.05	± 0.25	m A
<b>C</b>	- 40°C 25°C	± 0.10	± 0.50	m A
Reaction time @ 10 % of I <sub>PN</sub>		< 500		ns
Response time <sup>2)</sup> @ 90 % of I <sub>P</sub>	N	< 1		μs
di/dt accurately followed	•	> 200		A/μs
Frequency bandwidth (- 1 dB)		DC 2	200	kHz
	Linearity  Offset current @ $\mathbf{I}_p = 0$ , $\mathbf{T}_A = 25$ Residual current 1) @ $\mathbf{I}_p = 0$ , aft Thermal drift of $\mathbf{I}_0$ Reaction time @ 10 % of $\mathbf{I}_{PN}$ Response time 2) @ 90 % of $\mathbf{I}_p$ di/dt accurately followed	Offset current @ $\mathbf{I}_{\rm p}$ = 0, $\mathbf{T}_{\rm A}$ = 25°C Residual current 10 @ $\mathbf{I}_{\rm p}$ = 0, after an overload of 3 x $\mathbf{I}_{\rm PN}$ Thermal drift of $\mathbf{I}_{\rm O}$ - 25°C + 85°C - 40°C 25°C Reaction time @ 10 % of $\mathbf{I}_{\rm PN}$ Response time 20 90 % of $\mathbf{I}_{\rm PN}$ di/dt accurately followed		

@ ± 15 V (± 5 %)

 $\pm 0.45$ 

#### General data

T <sub>A</sub>	Ambient operating temperature		- 40 + 85	°C
T <sub>s</sub>	Ambient storage temperature		- 50 + 95	°C
$\mathbf{R}_{\mathrm{s}}$	Secondary coil resistance @	$T_{A} = 70^{\circ}C$	120	$\Omega$
Ü		$T_A = 85^{\circ}C$	128	$\Omega$
m	Mass		18	g
	Standards 3)		EN 50178 (97.10.01)	

 $I_{PN} = 100 A$ 



#### **Features**

- Closed loop (compensated) current transducer using the Hall effect
- · Printed circuit board mounting
- Insulated plastic case recognized according to UL 94-V0.

#### **Advantages**

- Excellent accuracy
- · Very good linearity
- Low temperature drift
- Optimized response time
- Wide frequency bandwidth
- No insertion losses
- High immunity to external interference
- Current overload capability.

#### **Applications**

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- AC variable speed drives and servo motor drives
- · Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

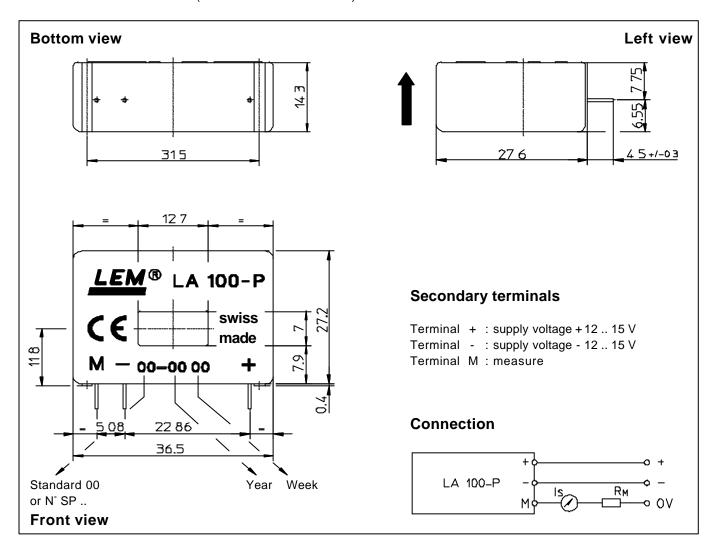
Notes: 1) The result of the coercive field of the magnetic circuit

- 2) With a di/dt of 100 A/µs
- <sup>3)</sup> A list of corresponding tests is available.

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#### **Dimensions LA 100-P** (in mm. 1 mm = 0.0394 inch)



#### **Mechanical characteristics**

General tolerance

Primary through-hole

Fastening & connection of secondary

Recommended PCB hole

± 0.2 mm

12.7 x 7 mm

3 pins

0.63 x 0.56 mm

0.9 mm

#### Remarks

- I<sub>s</sub> is positive when I<sub>p</sub> flows in the direction of the arrow.
- Temperature of the primary conductor should not exceed 100°C
- Dynamic performances (di/dt and response time) are best with a single bar completely filling the primary hole.
- In order to achieve the best magnetic coupling, the primary windings have to be wound over the top edge of the device.
- This is a standard model. For different versions (supply voltages, turns ratios, unidirectional measurements...), please contact us.